

Features

- ✧ UL Recognized File # E-326243
- ✧ Glass passivated chip junction
- ✧ High efficiency, Low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ For use in low voltage, high frequency inverter, free wheeling, and polarity protection application
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode



Mechanical Data

- ✧ Cases: ITO-220AC Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Terminals: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: As marked
- ✧ High temperature soldering guaranteed: 260°C / 0.25", (6.35mm) from case for 10 seconds
- ✧ Mounting torque: 5 in-lbs. max
- ✧ Weight: 1.74 grams

Ordering Information(example)

Part No.	Package	Packing	Packing code	Packing code (Green)
HERAF801G	ITO-220AC	50 / TUBE	C0	C0G

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Parameter	Symbol	HERAF 801G	HERAF 802G	HERAF 803G	HERAF 804G	HERAF 805G	HERAF 806G	HERAF 807G	HERAF 808G	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current	I _{F(AV)}	8								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	150								A
Maximum Instantaneous Forward Voltage (Note 1) @ 8 A	V _F	1.0				1.3	1.7			V
Maximum DC Reverse Current @ T _A =25 °C at Rated DC Blocking Voltage @ T _A =125 °C	I _R	10 400								uA uA
Maximum Reverse Recovery Time (Note 2)	T _{rr}	50					80			nS
Typical Junction Capacitance (Note 3)	C _j	80					60			pF
Typical Thermal Resistance	R _{θJC}	2								°C/W
Operating Temperature Range	T _J	- 55 to + 150								°C
Storage Temperature Range	T _{STG}	- 55 to + 150								°C

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

RATINGS AND CHARACTERISTIC CURVES (HERAF801G THRU HERAF808G)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

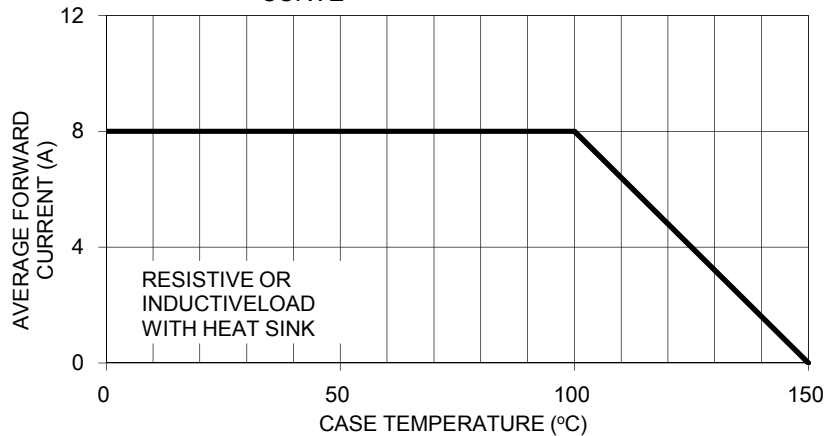


FIG. 3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

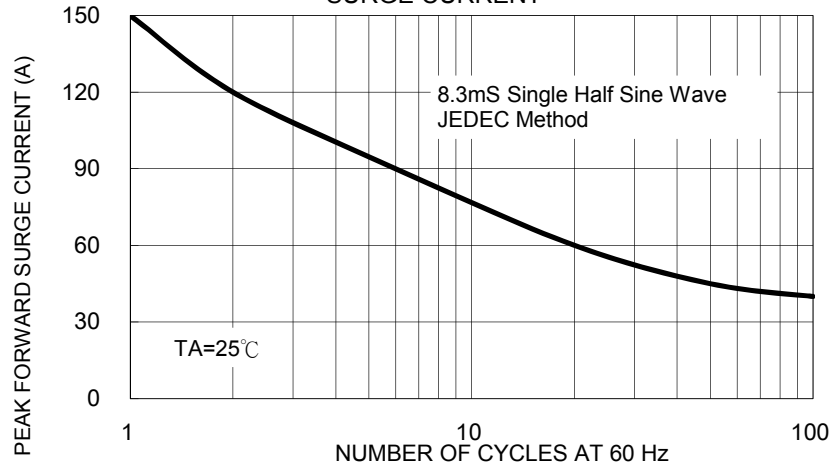


FIG. 4- TYPICAL JUNCTION CAPACITANCE

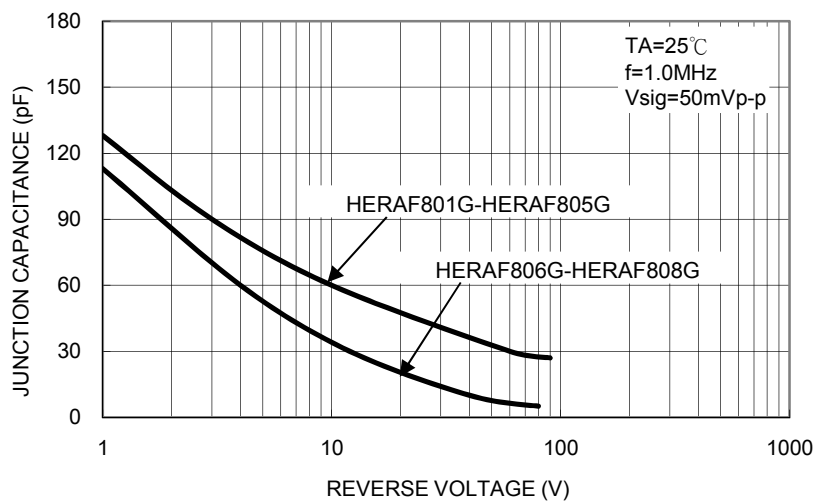


FIG. 2- TYPICAL REVERSE CHARACTERISTICS

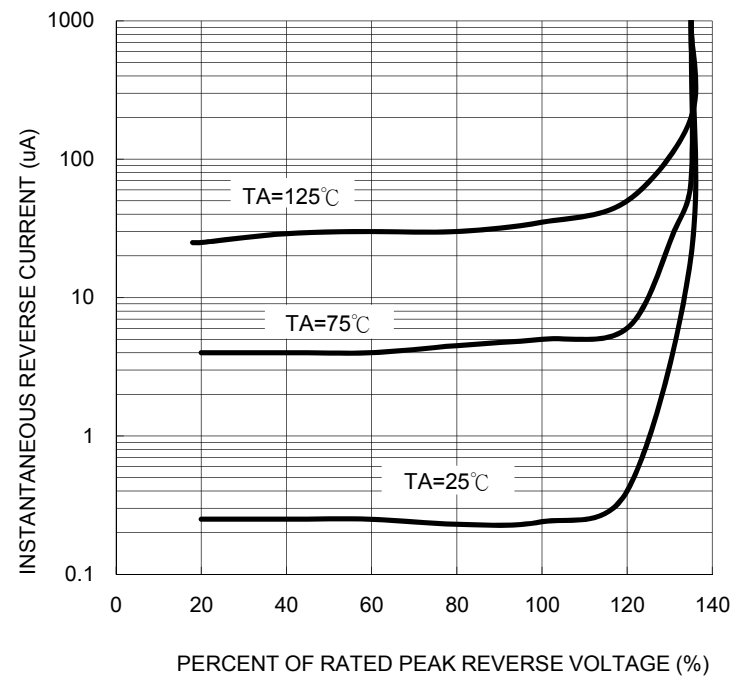


FIG. 5- TYPICAL FORWARD CHARACTERISTICS

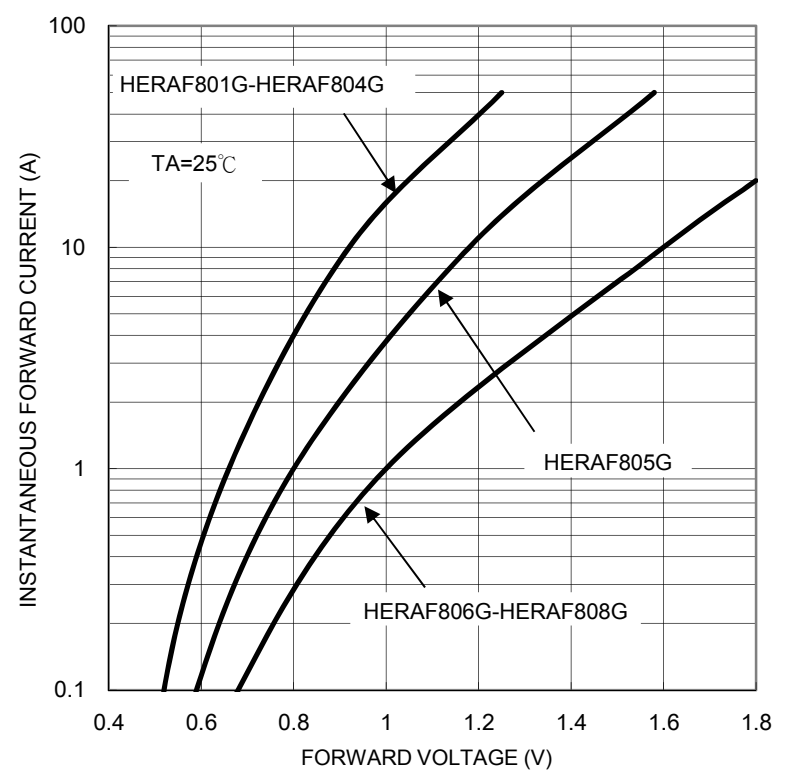
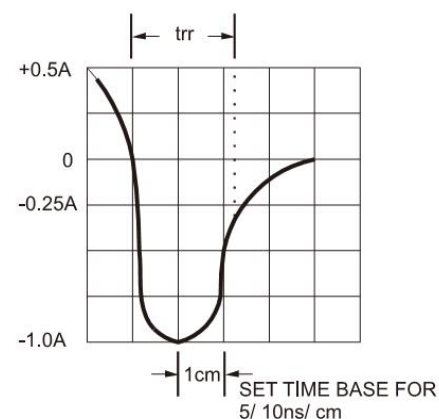
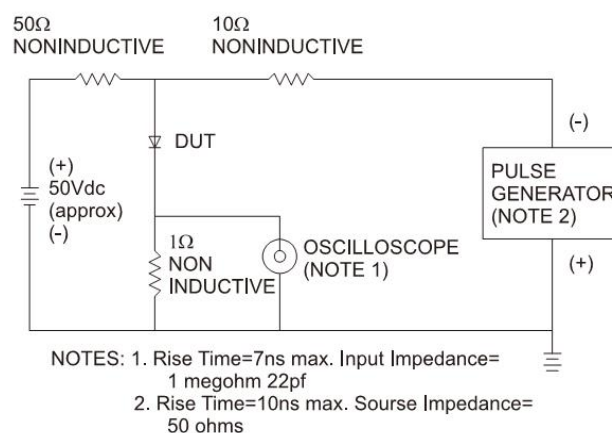


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

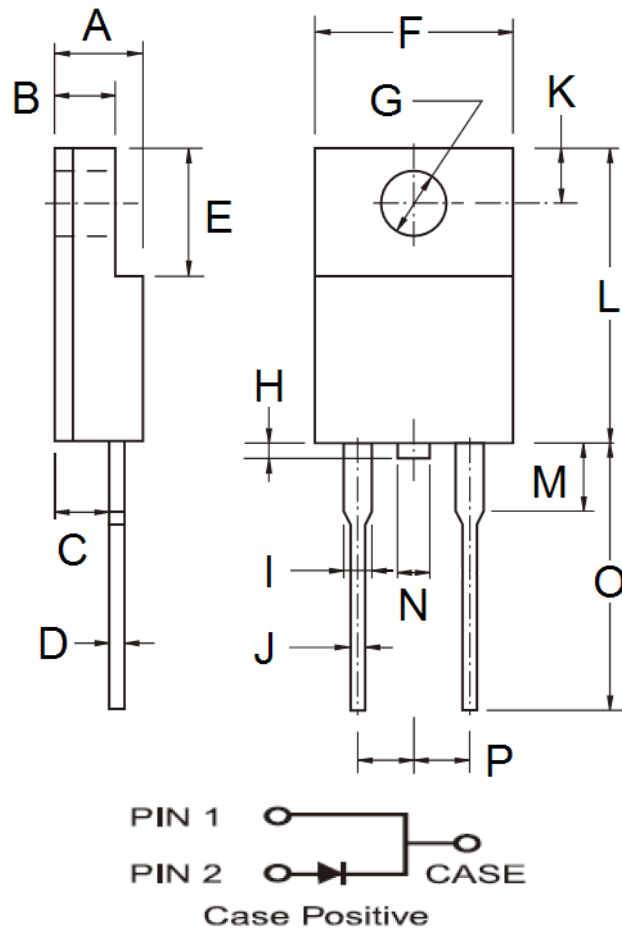


Ordering information

Part No.	Package	BULK Packing	Packing code	Packing code (Green)
HERAF80xG	ITO-220AC	50 / TUBE	C0	C0G

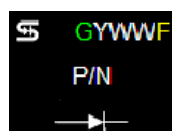
Note: "x" is Device Code from "1" thru "8".

Dimensions



DIM.	Unit(mm)		Unit(inch)	
	Min	Max	Min	Max
A	4.30	4.70	0.169	0.185
B	2.50	3.10	0.098	0.122
C	2.30	2.90	0.091	0.114
D	0.46	0.76	0.018	0.030
E	6.30	6.90	0.248	0.272
F	9.60	10.30	0.378	0.406
G	3.00	3.40	0.118	0.134
H	-	1.60	-	0.063
I	0.95	1.45	0.037	0.057
J	0.50	0.90	0.020	0.035
K	2.40	3.20	0.094	0.126
L	14.80	15.50	0.583	0.610
M	-	4.10	-	0.161
N	-	1.80	-	0.071
O	12.60	13.80	0.496	0.543
P	4.95	5.20	0.195	0.205

Marking Diagram



P/N = Specific Device Code
G = Green Compound
YWW = Date Code
F = Factory Code

Mouser Electronics

Authorized Distributor

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